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TOSHIBA GTR Module Silicon N Channel IGBT

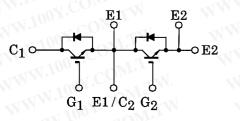
# MG300J2YS50

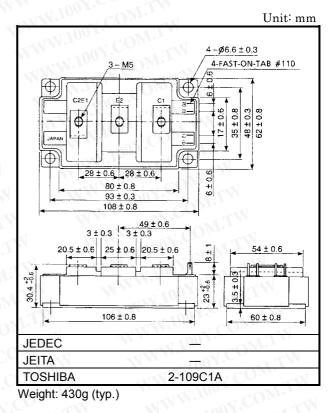
High Power Switching Applications Motor Control Applications

- The electrodes are isolated from case.
- High input impedance
- Includes a complete half bridge in one package.
- Enhancement-mode
- High speed :  $t_f = 0.30 \mu s (max) (I_C = 300A)$  $t_{rr} = 0.15 \mu s (max) (I_F = 300A)$
- Low saturation voltage

:  $V_{CE}$  (sat) = 2.70V (max) (IC = 300A)

#### **Equivalent Circuit**





#### Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Collector-emitter voltage Gate-emitter voltage		V <sub>CES</sub>	600	O V
		V <sub>GES</sub>	±20	V
Collector current	DC	I <sub>C</sub>	300	CA
	1ms	I <sub>CP</sub>	600	
Forward current	DC	IF	300	A
	1ms	IFM	600	
Collector power dissipation (Tc = 25°C)		Pc	1300	W
Junction temperature		Тј	150	°C
Storage temperature r	ange	T <sub>stg</sub>	-40 ~ 125	°C
Isolation voltage		V <sub>Isol</sub>	2500 (AC 1 min.)	v
Screw torque (Terminal / mounting)		CONT.	3/3	N∙m

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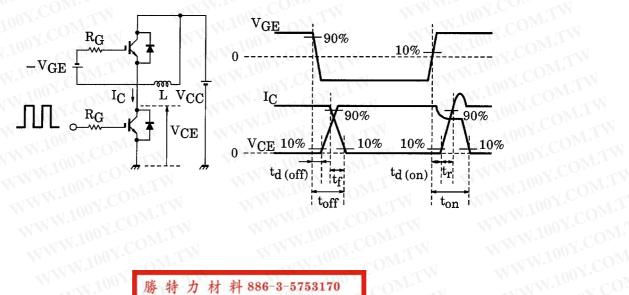
Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I <sub>GES</sub>	V <sub>GE</sub> = ±20V, V <sub>CE</sub> = 0		—	±500	nA
Collector cut-off current		ICES	V <sub>CE</sub> = 600V, V <sub>GE</sub> = 0		_	2.0	mA
Gate-emitter cut-off voltage		V <sub>GE</sub> (off)	I <sub>C</sub> = 30mA, V <sub>CE</sub> = 5V		7.0	8.0	V
Collector-emitter saturation voltage		V <sub>CE (sat)</sub>	I <sub>C</sub> = 300A, V <sub>GE</sub> = 15V		2.10	2.70	V
Input capacitance		Cies	V <sub>CE</sub> = 10V, V <sub>GE</sub> = 0, f = 1MHz		30800		pF
Switching time	Turn-on delay time	t <sub>d (on)</sub>	N N N. 100 X C	$0\overline{N}$	0.20	0.40	μs
	Rise time	tr	Inductive load $V_{CC} = 300V$ $I_C = 300A$ $V_{GE} = \pm 15V$ $R_G = 1.8\Omega$	MO.	0.15	0.30	
	Turn-on time	ton			0.60	1.20	
	Turn-off delay time	td (off)		<u> </u>	0.20	0.40	
	Fall time	tf	(Note 1)		0.15	0.30	
	Turn-off time	toff			0.50	1.00	
Forward voltage		VF	I <sub>F</sub> = 300 A, V <sub>GE</sub> = 0	, <del>T</del>	2.30	3.00	V
Reverse recovery time		trr	I <sub>F</sub> = 300 A, V <sub>GE</sub> = -10 V, di / dt = 400 A / μs	100X	0.08	0.15	μs
Thermal resistance		R <sub>th (j-c)</sub>	Transistor stage	1001		0.096	°C / 1
			Diode stage		N CO	0.20	°C/W

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Note 1: Switching time test circuit & timing chart

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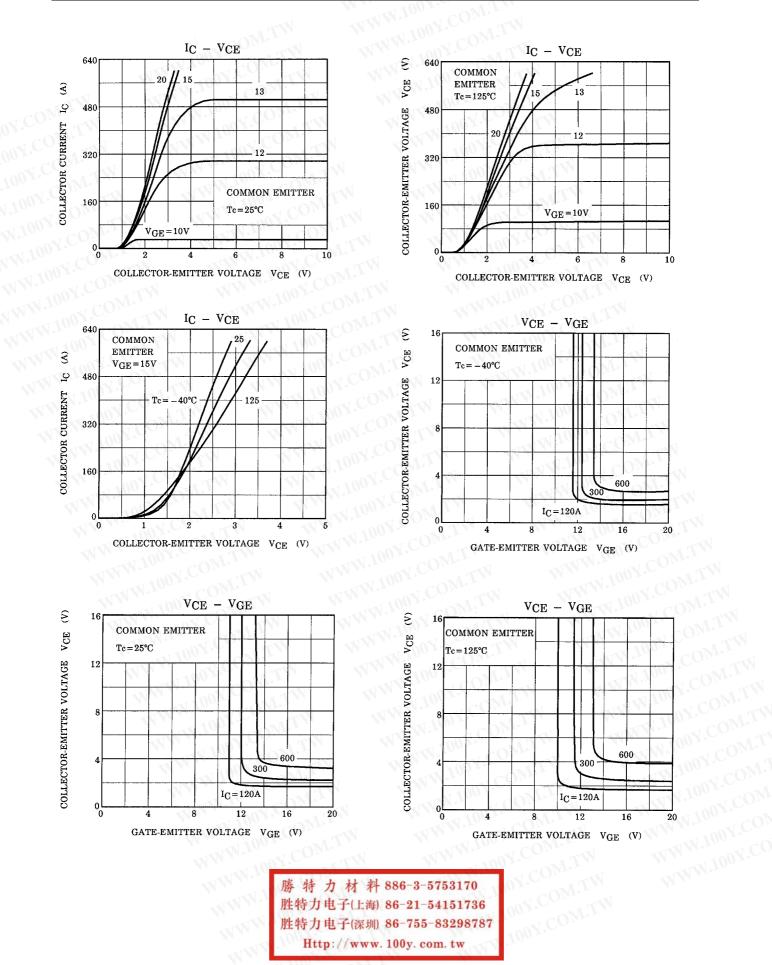
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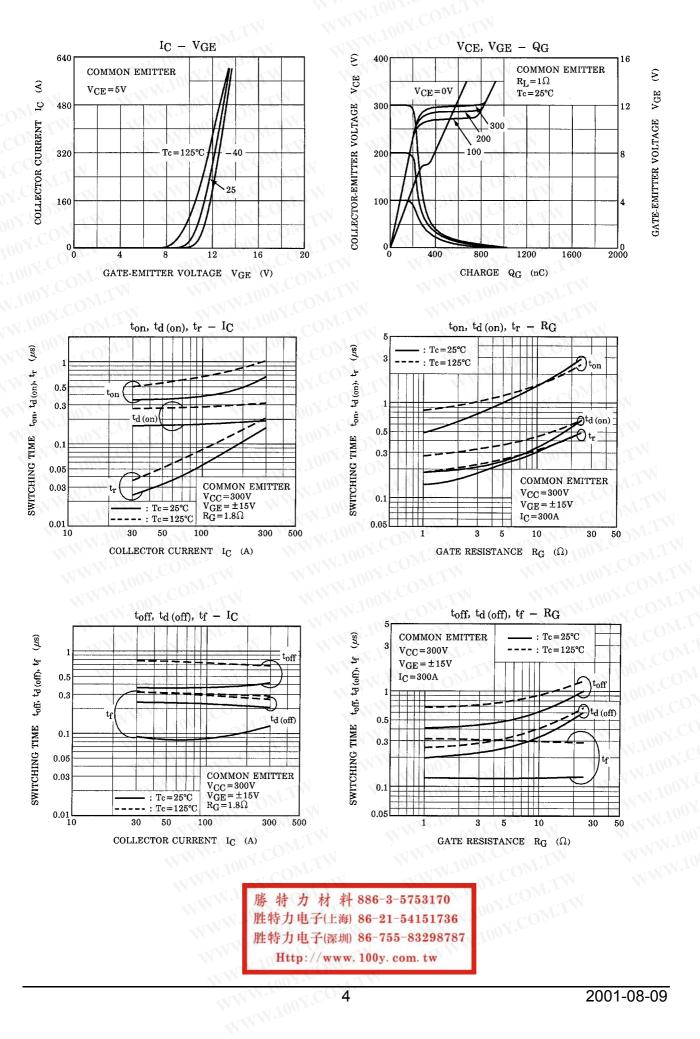
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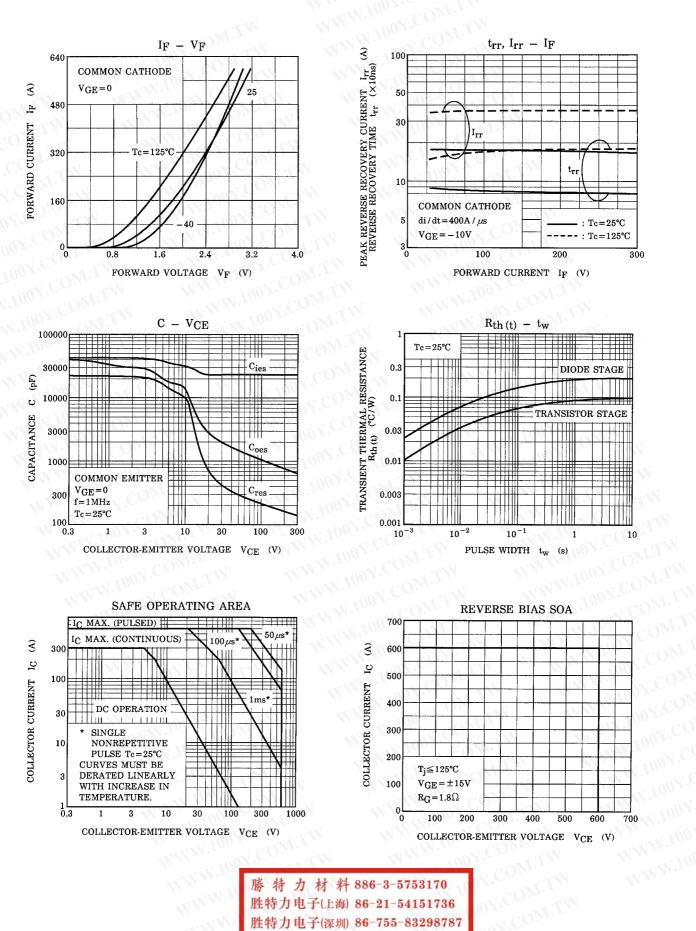
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